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1. Global joint venture starts operations as WeEn Semiconductors

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As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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WeEn Semiconductors



Product data sheet

1. General description

Dual ultrafast power diode in a SOT429 (3-lead TO-247) plastic package.

2. Features and benefits

- Very low on-state loss
- Fast switching
- Soft recovery characteristic minimizes power consuming oscillations
- High reverse surge capability
- High thermal cycling performance
- Low thermal resistance

3. Applications

Output rectifiers in high-frequency switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	200	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 113 °C; square-wave pulse; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	15	Α
I _{O(AV)}	average output current	δ = 0.5 ; T _{mb} ≤ 104 °C; square-wave pulse; both diodes conducting	-	-	30	Α
I _{RSM}	non-repetitive peak reverse current	t_p = 100 µs; per diode	-	-	0.2	Α
Static chara	acteristics					
V _F	forward voltage	I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>	-	0.78	0.9	V
Dynamic ch	naracteristics					,
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7	-	20	28	ns





5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		A1 A2
2	K	cathode		
3	A2	anode 2		sym125
mb	К	mounting base; cathode		
			TO-247 (SOT429)	

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYV72EW-200	TO-247	plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3 lead TO-247	SOT429

7. Marking

Table 4. Marking codes

Type number	Marking code
BYV72EW-200	BYV72EW-200

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	200	V
V_{RWM}	crest working reverse voltage		-	200	V
V_R	reverse voltage	T _{mb} ≤ 144 °C; DC	_	200	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 113 °C; square-wave pulse; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	15	А
I _{O(AV)}	average output current	δ = 0.5 ; T _{mb} ≤ 104 °C; square-wave pulse; both diodes conducting	-	30	Α

BYV72EW-200

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Dual ultrafast power diode

Symbol	Parameter	Conditions	Min	Max	Unit
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; <u>Fig. 4</u>	-	170	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; <u>Fig. 4</u>	-	185	А
I _{RRM}	repetitive peak reverse current	δ = 0.001 ; t_p = 2 μ s; per diode	-	0.2	Α
I _{RSM}	non-repetitive peak reverse current	t_p = 100 µs; per diode	-	0.2	Α
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C
Electrostatic d	lischarge				,
V _{ESD}	electrostatic discharge voltage	HBM; C = 250 pF; R = 1.5 kΩ	-	8	kV

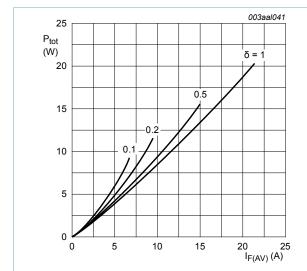


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; per diode; maximum values

$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_{O} &= 0.744 \text{ V; } R_{S} = 0.010 \text{ } \Omega \end{split}$$

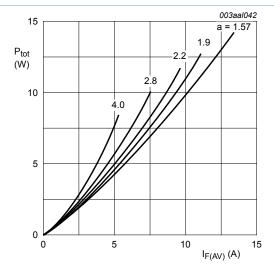


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; per diode; maximum values

a = form factor =
$$I_{F(RMS)}/I_{F(AV)}$$

 $V_O = 0.744 \text{ V}; R_S = 0.010 \Omega$

Dual ultrafast power diode

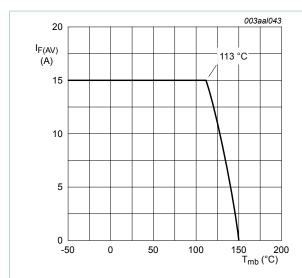


Fig. 3. Average forward current as a function of mounting base temperature; per diode; maximum values

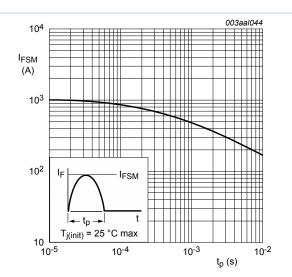


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; per diode; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
from junct	thermal resistance from junction to	with heatsink compound; per diode; Fig. 5	-	-	2.4	K/W
	mounting base	with heatsink compound; both diodes conducting	-	-	1.4	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	45	-	K/W

Dual ultrafast power diode

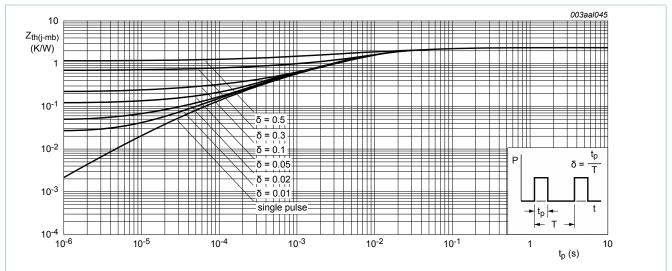


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse width; per diode; maximum values

10. Characteristics

Table 7. Characteristics

characteristics are per diode unless otherwise stated

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static charac	Static characteristics							
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; <u>Fig. 6</u>		-	0.95	1.05	V	
		I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>		-	1	1.2	V	
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>		-	0.78	0.9	V	
I _R	reverse current	V _R = 200 V; T _j = 25 °C		-	10	100	μA	
		V _R = 200 V; T _j = 100 °C		-	0.5	1	mA	
Dynamic cha	racteristics							
Q _r	recovered charge	$I_F = 2 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 20 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	6	15	nC	
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/µs}$; $T_j = 25 \text{ °C}$; Fig. 7		-	20	28	ns	
V_{FRM}	forward recovery voltage	$I_F = 1 \text{ A}; dI_F/dt = 10 \text{ A/}\mu\text{s}; T_j = 25 °C;$ Fig. 8		-	1	-	V	

Dual ultrafast power diode

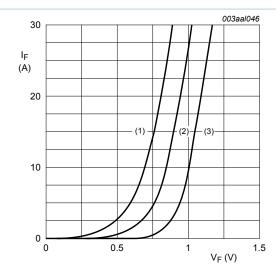


Fig. 6. Forward current as a function of forward voltage; per diode

(1) $T_j = 150$ °C; typical values; (2) $T_j = 150$ °C; maximum values; (3) $T_j = 25$ °C; maximum values; $V_O = 0.744$ V; $R_S = 0.010$ Ω

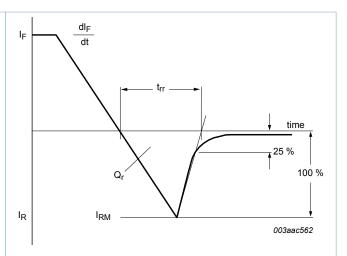


Fig. 7. Reverse recovery definitions; ramp recovery

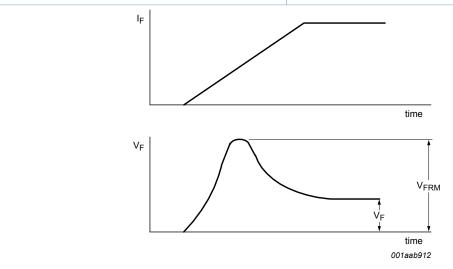
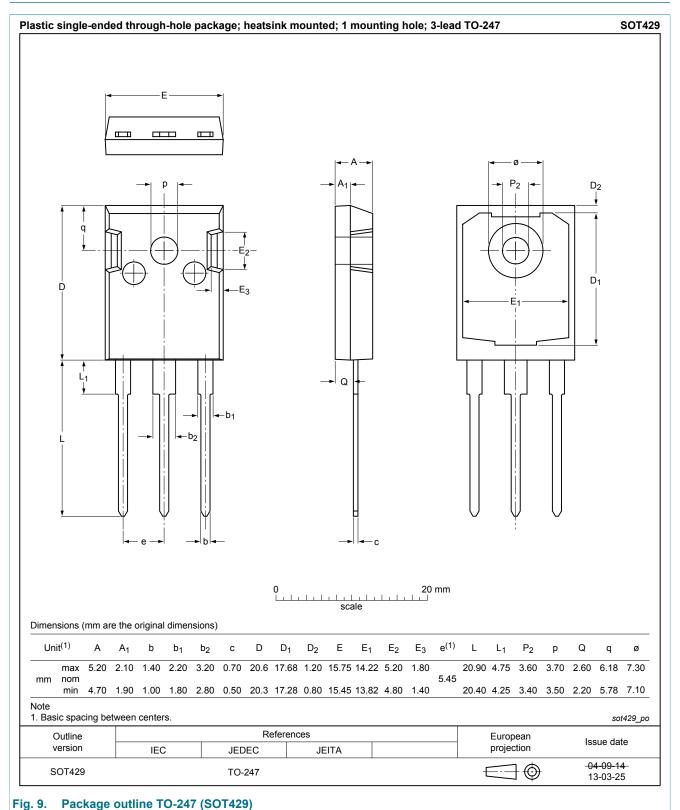


Fig. 8. Forward recovery definitions

11. Package outline



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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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